## NSN 5961-01-343-3641

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View Online at https://aerobasegroup.com/nsn/5961-01-343-3641

**Inclosure Material:** 

Metal

**Overall Length:** 

Between 0.240 inches and 0.260 inches

**Terminal Length:** 

0.500 inches

**Overall Diameter:** 

Between 0.335 inches and 0.370 inches

**Internal Configuration:** 

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-39

**Electrode Internally-electrically Connected To Case:** 

Collector

**Mounting Method:** 

Terminal

**Terminal Circle Diameter:** 

0.200 inches

**Features Provided:** 

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-50.0 collector to base voltage/static/emitter open and -50.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open

**Current Rating Per Characteristic:** 

-1.00 amperes source cutoff current

**Power Rating Per Characteristic:** 

5.0 watts small-signal input power, common-collector preset

**Transfer Ratio:** 

25.0 static forward current transfer ratio, common-emitter

**Maximum Operating Tempurature Per Measurement Point:** 

200.0 degrees celsius junction

**Special Features:** 

Junction pattern arrangement: pnp

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

**Terminal Type And Quantity:** 

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/348 government specification

Shelf Life:

NI/o

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Demilitarization:

No

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